

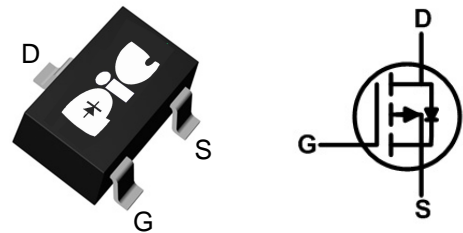
➤ General Description

This PAP3433R P-Channel enhancement mode power field effect transistor is the high density trench technology and this advanced technology can provide excellent $R_{ds(On)}$ performance and efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

➤ Feature

- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability
- SOT-323 package design

➤ SOT-323



➤ Application

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- Net Working System

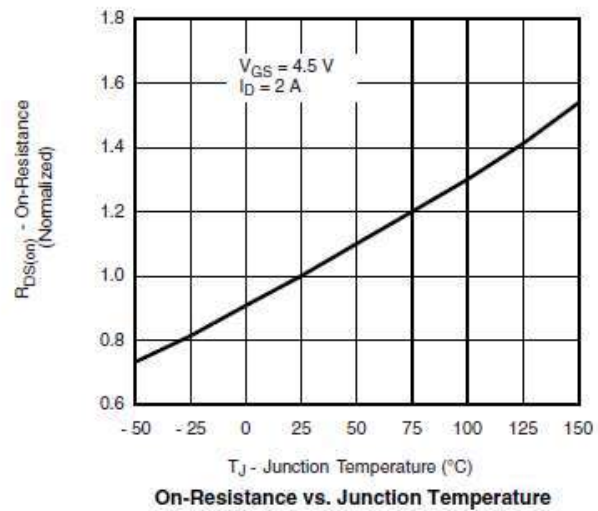
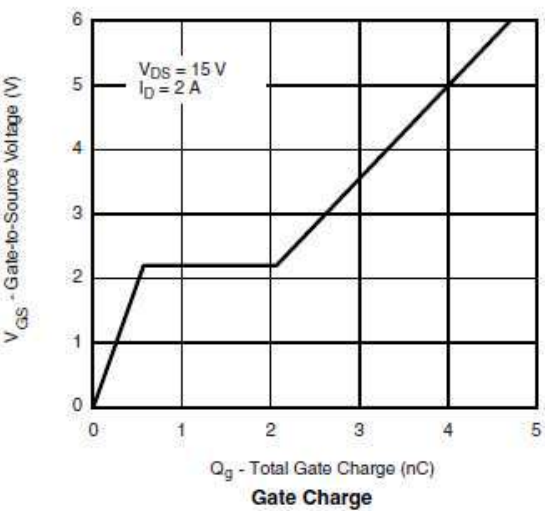
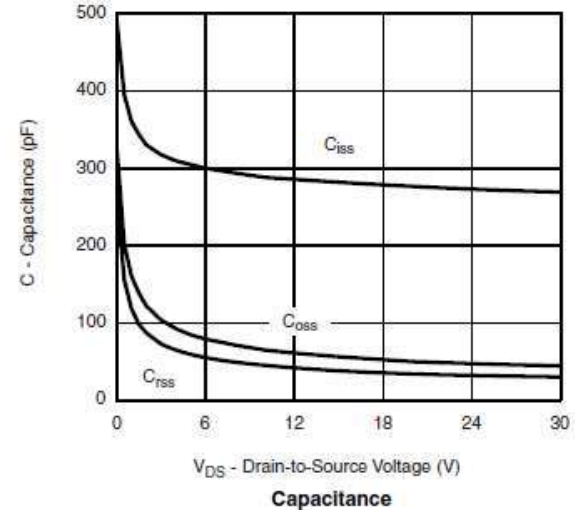
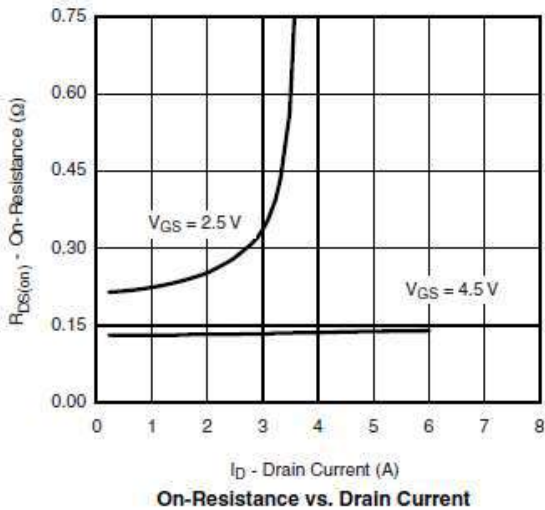
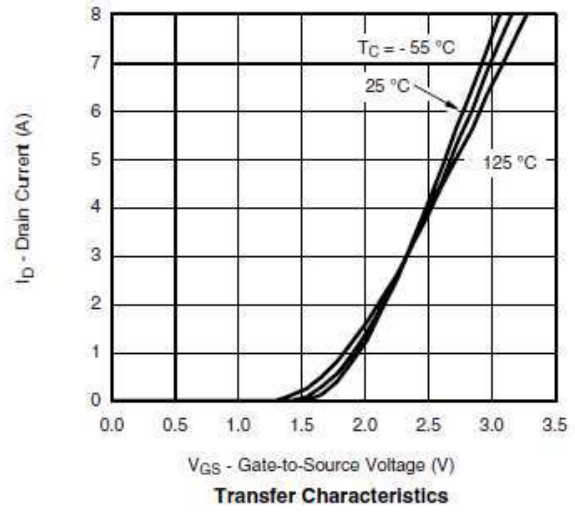
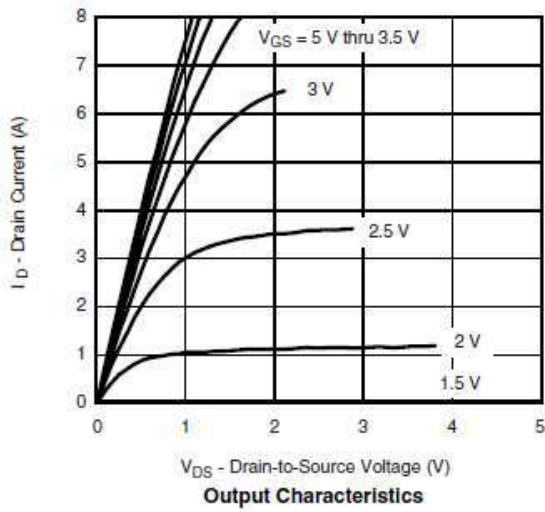
➤ Absolute Maximum Ratings

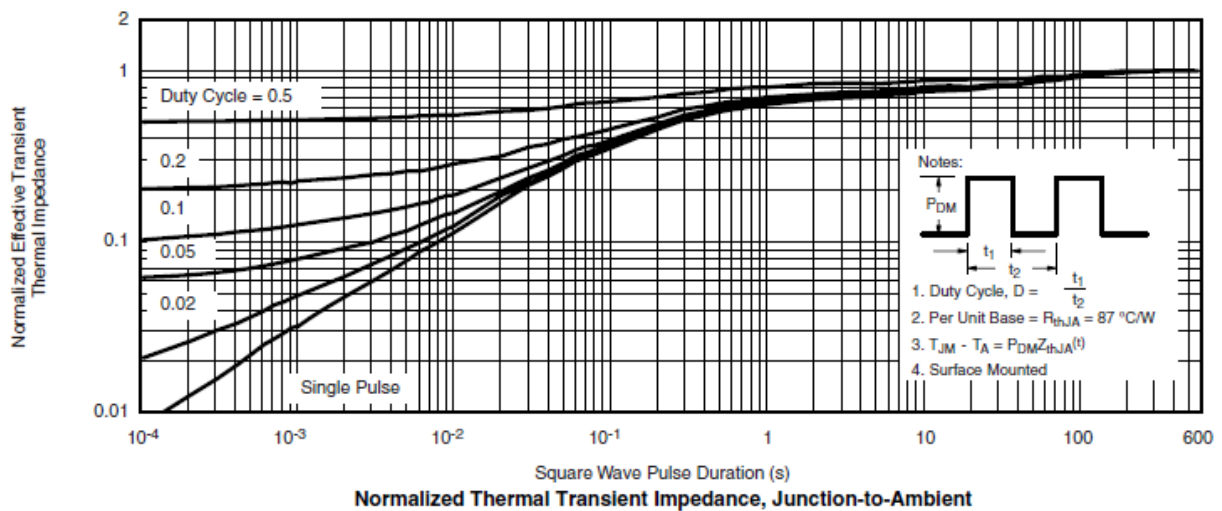
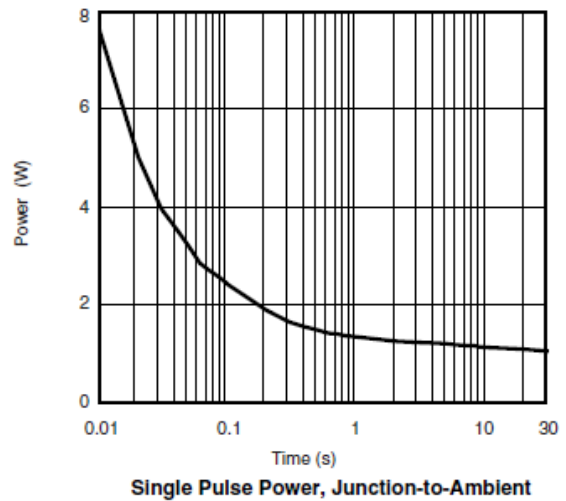
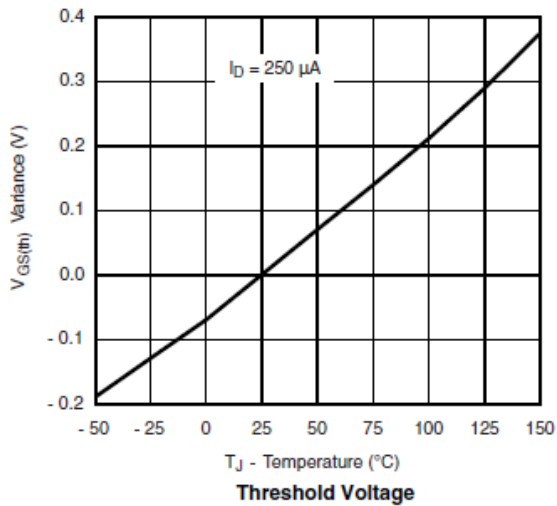
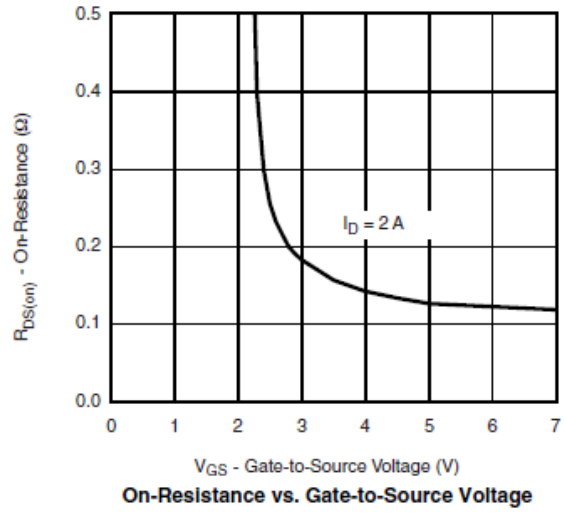
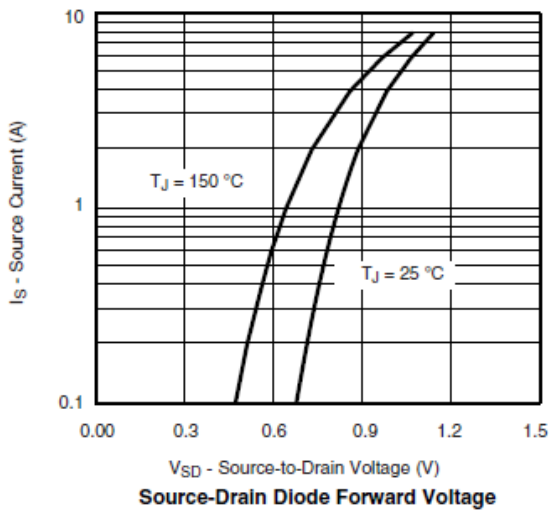
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-30	V
Gate –Source Voltage	V_{GSS}	± 20	V
Continuous Drain Current($T_J=150^\circ C$)	I_D	$T_A=25^\circ C$	-3.0
		$T_A=70^\circ C$	-2.4
Pulsed Drain Current	I_{DM}	-10	A
Continuous Source Current(Diode Conduction)	I_S	-1.6	A
Power Dissipation	P_D	$T_A=25^\circ C$	0.35
		$T_A=70^\circ C$	0.22
Operating Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{STG}	-55/150	$^\circ C$
Thermal Resistance-Junction to Ambient	$R_{\theta JA}$	120	$^\circ C / W$

➤ **Electrical Characteristics ($T_A=25^\circ C$ Unless otherwise noted)**

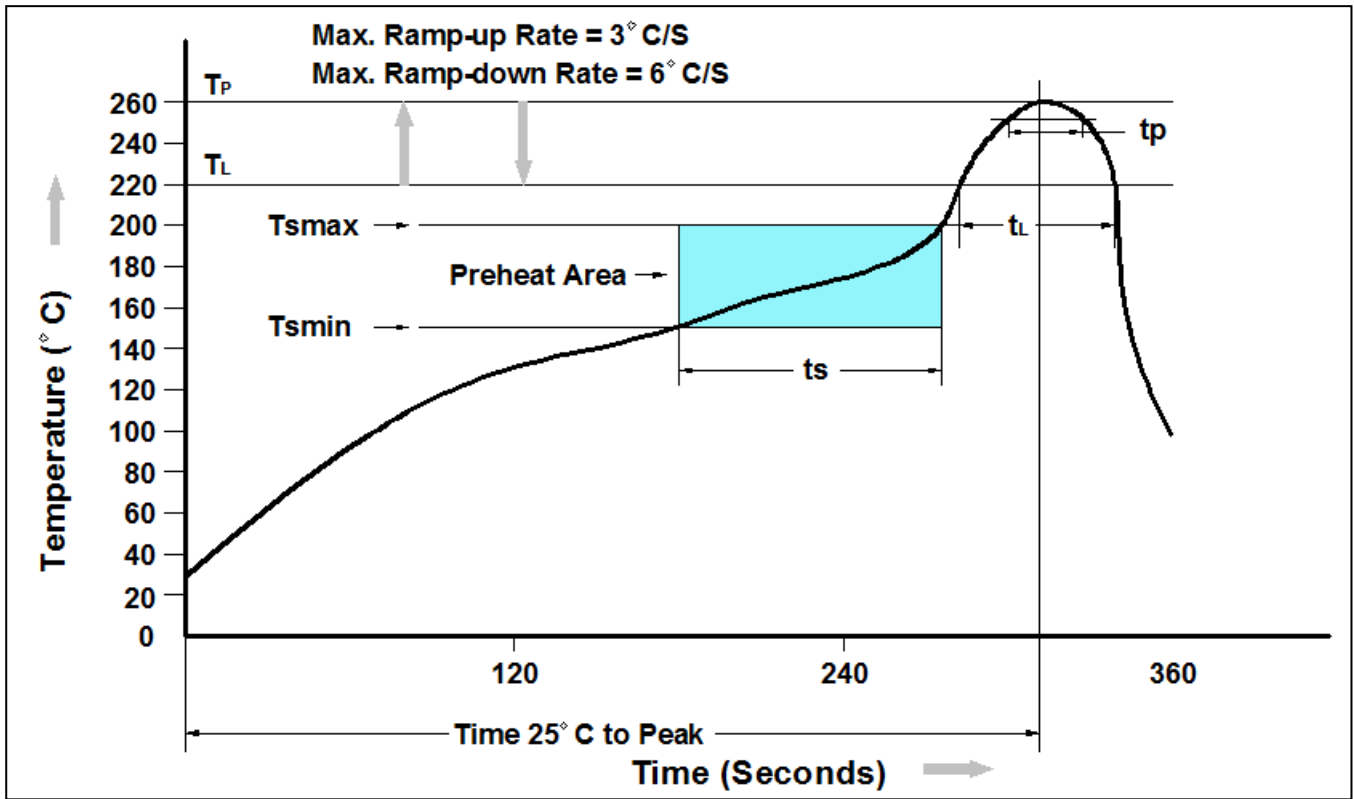
Parameter	Symbol	Conditions	Min.	Typ	Max.	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0		-2.5	
Gate Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-24V, V_{GS}=0V$			-1	uA
		$V_{DS}=-24V, V_{GS}=0V$ $T_A=85^\circ C$			-30	
On-State Drain Current	$I_{D(on)}$	$V_{DS} \leq -5V, V_{GS}=-10V$	-10			A
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-3.0A$		135	150	m Ω
		$V_{GS}=-4.5V, I_D=-2.6A$		170	185	
Forward Transconductance	g_{FS}	$V_{DS}=-5V, I_D=-2.0A$		10		S
Diode Forward Voltage	V_{SD}	$I_S=-0.6A, V_{GS}=0V$		-0.7	-1.3	V
Dynamic						
Total Gate Charge	Q_g	$V_{DS}=-15V, V_{GS}=-4.5V, I_D=-2.0A$		4	6	nC
Gate-Source Charge	Q_{gs}		0.6			
Gate-Drain Charge	Q_{gd}		1.5			
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V$ $f=1MHz$		230		pF
Output Capacitance	C_{oss}		40			
Reverse Transfer Capacitance	C_{rss}		25			
Turn-On Time	$t_{d(on)}$	$V_{DD}=-15V, R_L=15\Omega$ $I_D=-2.0A, V_{GEN}=-10V, R_G=6\Omega$		5	10	ns
	t_r			8	15	
Turn-Off Time	$t_{d(off)}$			15	30	
	t_f		15	30		

➤ Typical Characteristics





➤ Recommand IR Reflow Soldering Thermal Profile

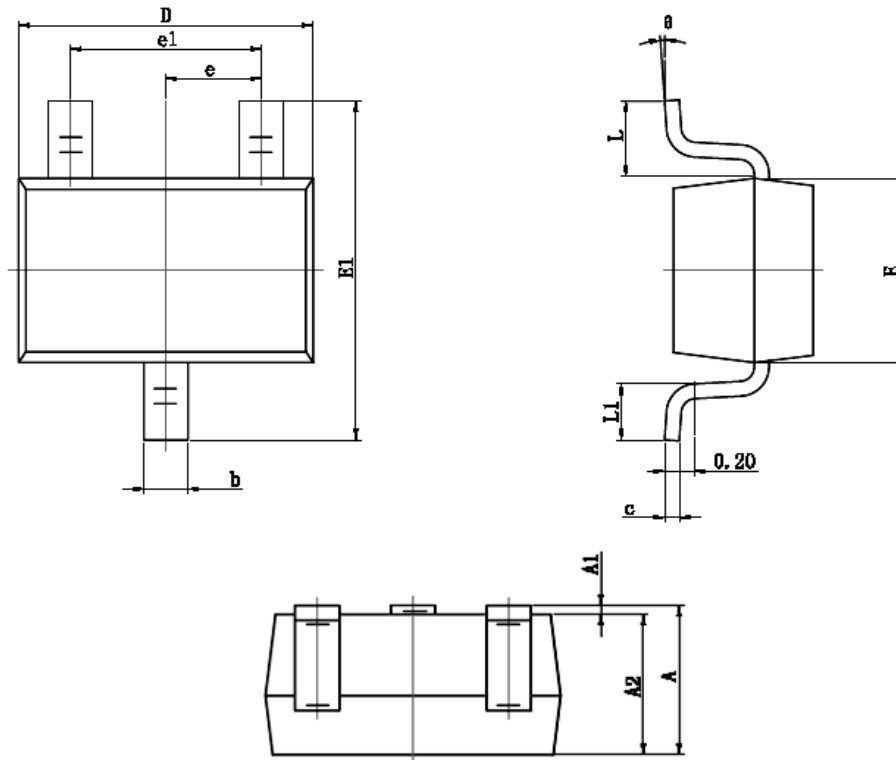


Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	150°C
Temperature Max. (T_{smax})	200°C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds
Average Ramp-up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds
Peak Temperature	260°C +0°C / -5°C
Time (t_P) within 5°C of actual Peak Temperature	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

➤ Ordering Information

Part Number	Description	Quantity
PAP3433R	SOT-323 Reel	3000 pcs

➤ Package Information (SOT-323)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

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